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Author Correction: Ultra-thin high-efficiency mid-infraredtransmissive Huygens meta-optics

Li Zhang^{1,2}, Jun Ding^{3,4}, Hanyu Zheng^{1,2}, Sensong An⁴, Hongtao Lin², Bowen Zheng⁴, Qingyang Du², Gufan Yin², Jerome Michon², Yifei Zhang², Zhuoran Fang², Mikhail Y. Shalaginov², Longjiang Deng¹, Tian Gu², Hualiang Zhang⁴ & Juejun Hu²

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This has been corrected in both the PDF and HTML versions of the Article.

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¹ State Key Laboratory of Electronic Thin Films and Integrated Devices, National Engineering Research Center of Electromagnetic Radiation Control Materials, University of Electronic Science and Technology of China, Chengdu, Sichuan 611731, China. ² Department of Materials Science & Engineering, Massachusetts Institute of Technology, Cambridge, MA 02139, USA. ³ School of Information and Science Technology, East China Normal University, Shanghai 200062, China. ⁴ Department of Electrical & Computer Engineering, University of Massachusetts Lowell, Lowell, MA 01854, USA. These authors contributed equally: Li Zhang, Jun Ding, Hanyu Zheng. Correspondence and requests for materials should be addressed to T.G. (email: gutian@mit.edu) or to H.Z. (email: hualiang_zhang@uml.edu) or to J.H. (email: hujuejun@mit.edu)